

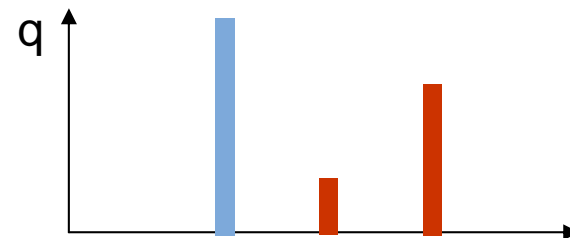
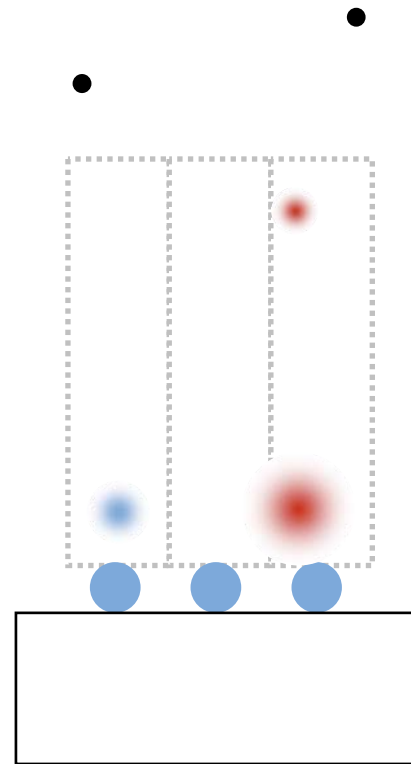
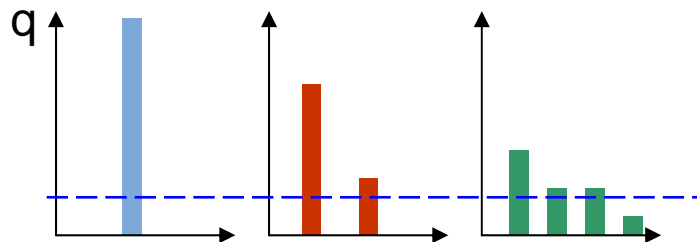
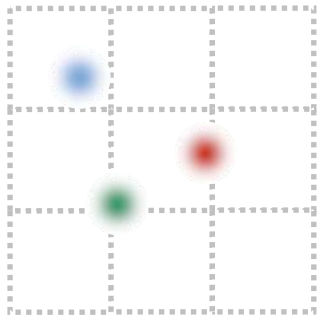
Correction of the charge sharing in photon-counting pixel detector data

Cyril Ponchut
ESRF

Outline

- Charge sharing
- Detector response model
- Spectrum reconstruction algorithm
- Results
- Conclusion

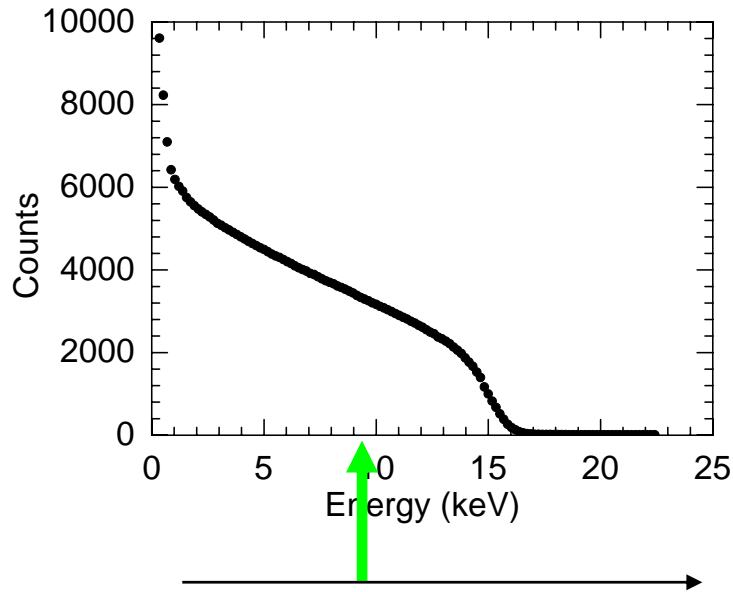
Charge sharing



For details : papers from B. Norlin, C. Frödjh, L. Tlustos, H. E. Nilsson, G.Pellegrini, A. Korn,...

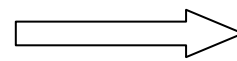
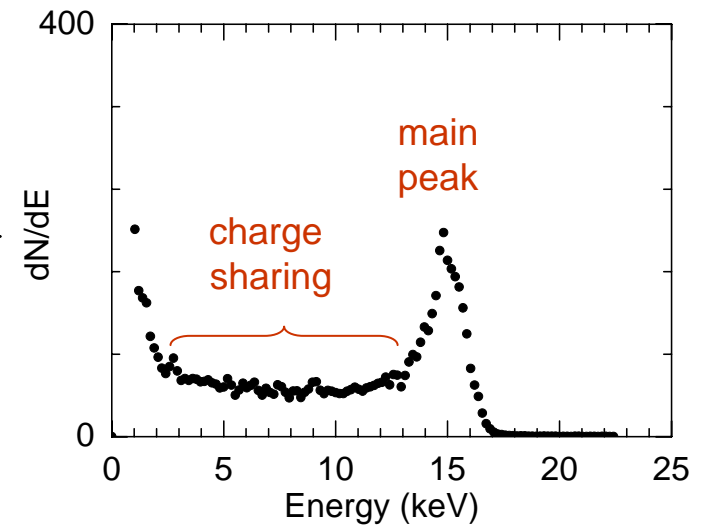
Energy spectra measurements

15 keV monoenergetic beam



threshold scan acquisition

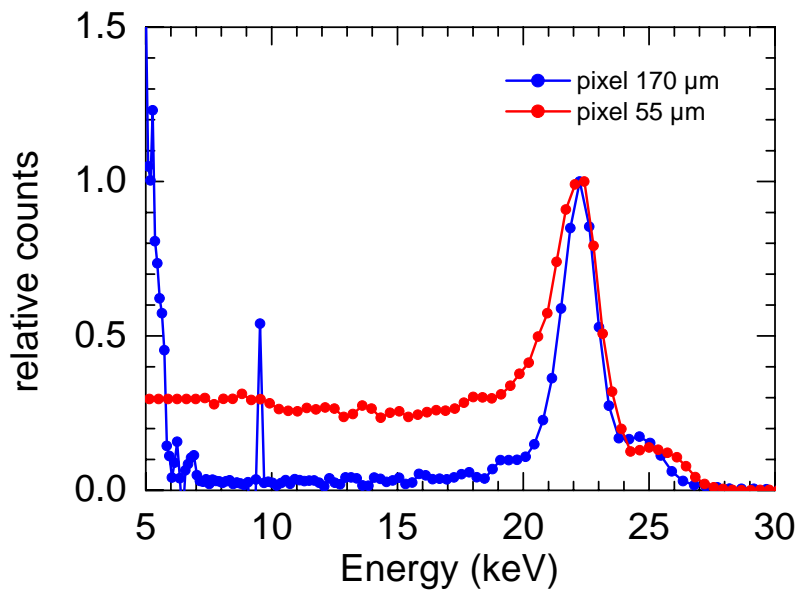
$\frac{dN}{dE}$

basic processing : S-curve differentiation

Effect of pixel size

^{109}Cd source spectrum (22.1 keV, 25 keV)



- Same sensor thickness (300 μm)
- Pixel sizes 55 μm and 170 μm

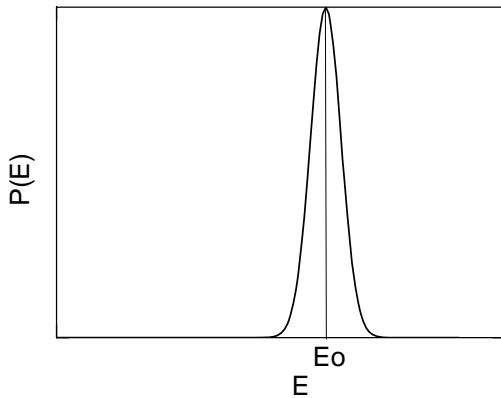
How to correct charge sharing ?

- Large pixels
- Medipix 3
- Timepix in TOT mode (V.Tichy's poster, J. Jakubek's talk)
- e.g. spectrum stripping (M. Firshing's talk)
- **this method**
- ...

Basic energy response model

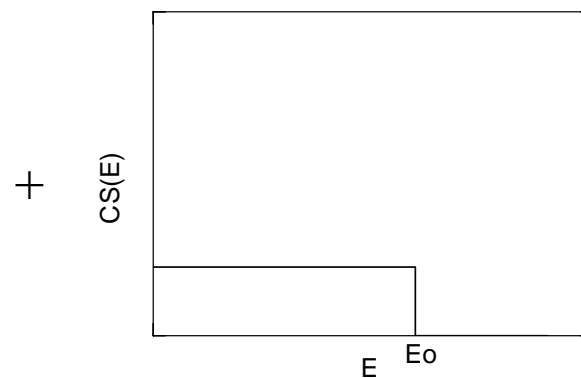
Monoenergetic incident beam

main peak
(unsplit events)

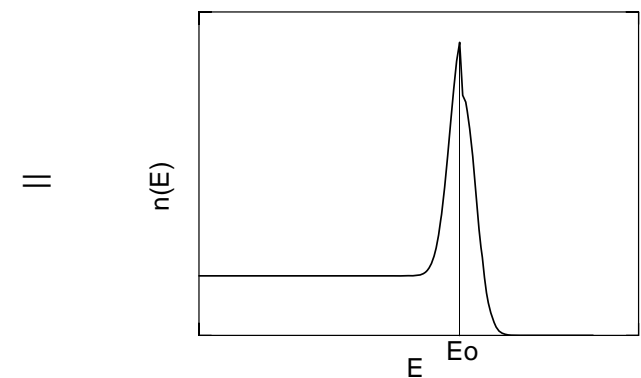


$$n_p(E) = \frac{I_p}{w\sqrt{\pi}} \exp\left(-\left(\frac{E - E_0}{w}\right)^2\right)$$

charge sharing
(splitted events)

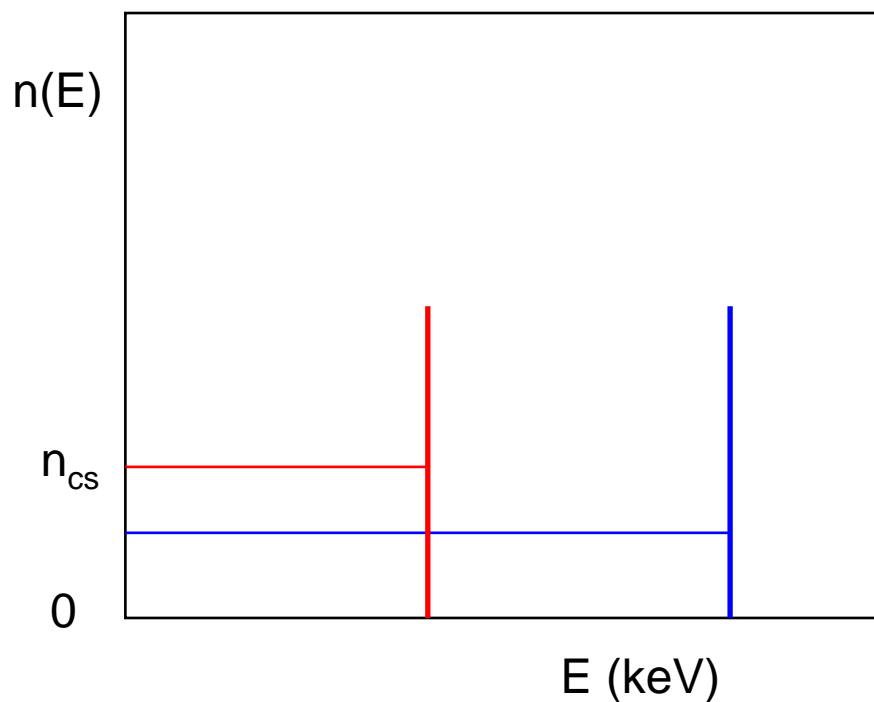


measured



$$n(E) = (1 - k) \cdot n_p(E) + k \cdot n_{cs}(E)$$

Model approximations



k = charge sharing probability for one absorbed photon

Approximation 1 : $k = n_{cs} \cdot E$

Approximation 2 : k independent of E

Hence for 1 absorbed photon of energy E :

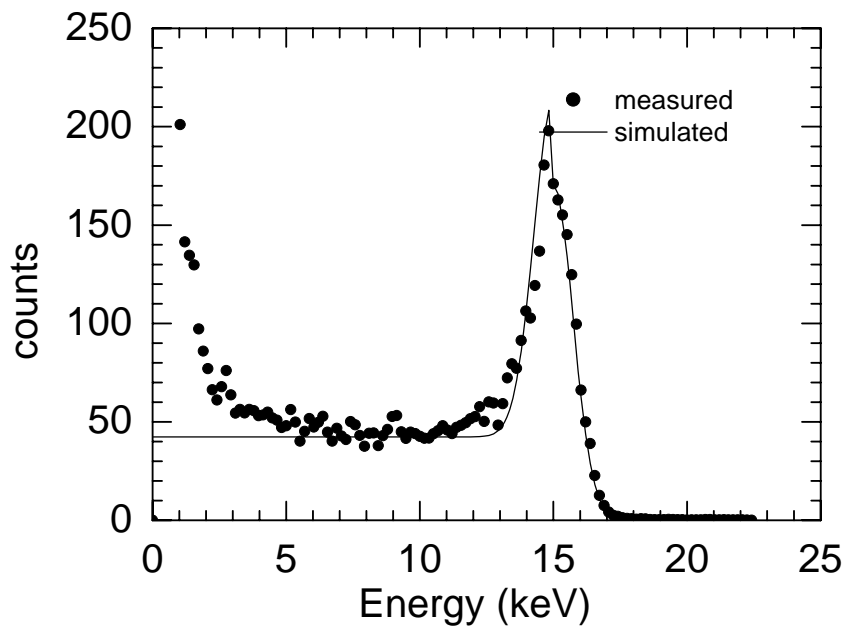
$$n_{cs}(E) = \frac{k}{E}$$

For $\Phi(E)$ absorbed monochromatic photons :

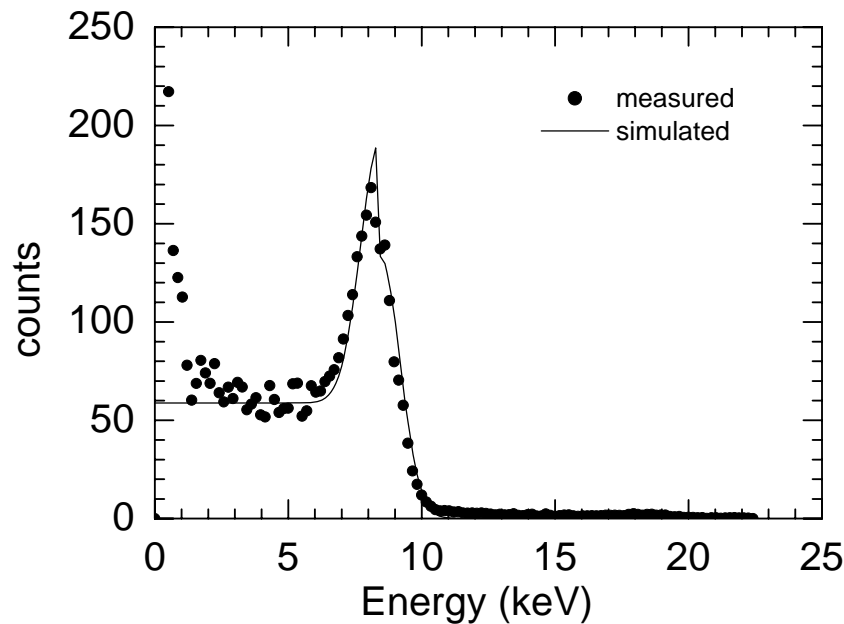
$$n_{cs}(E) = k \frac{\phi(E)}{E}$$

Model fitting

15 keV



8.62 keV



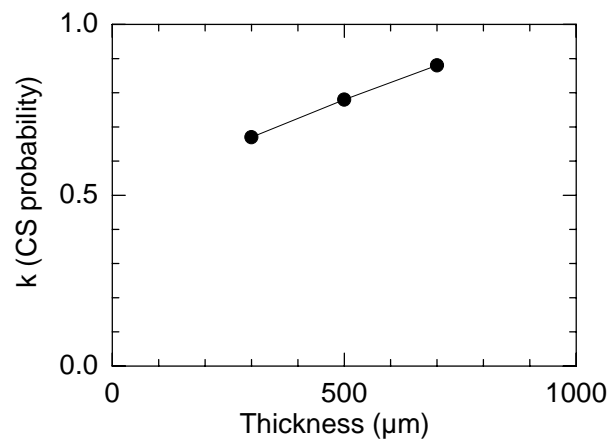
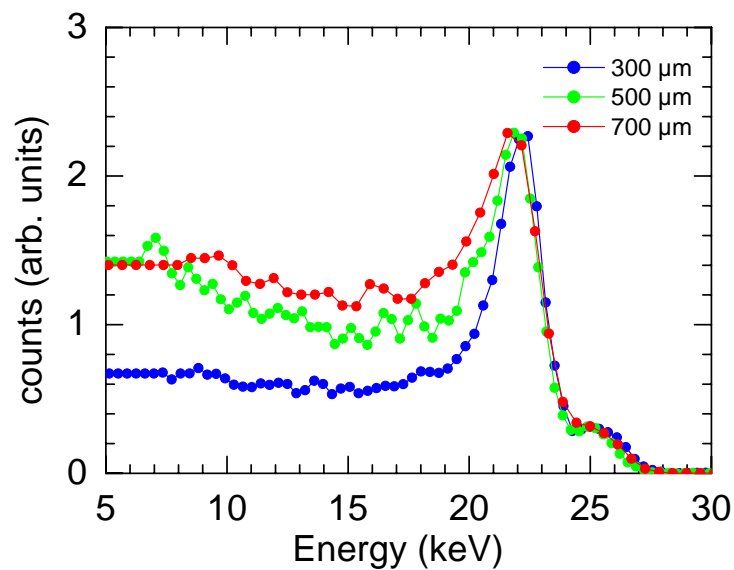
Same fitting parameters at different energies :

- k charge sharing = 0.67
- w peak = 1.03 keV (1/e)

=> validation of model

Effect of sensor thickness

Source : ^{109}Cd



charge sharing probability vs. thickness

Response for any input spectrum

Absorbed X-rays spectrum $\Phi(E)$

Measured spectrum $N(E)$

$$N(E) = (1 - k) \int_{-\infty}^{+\infty} P(E - E_0) \cdot \Phi(E_0) dE_0 + k \int_E^{+\infty} \frac{\Phi(E_0)}{E_0} dE_0$$

main peak
(unsplitted events)
charge sharing

linearity with respect to $\Phi \Rightarrow$

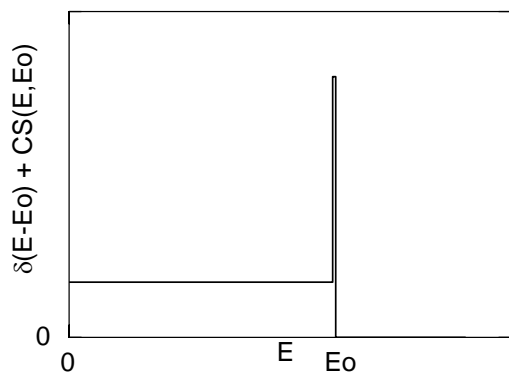
$$N = H\Phi$$

finite approximation \Rightarrow

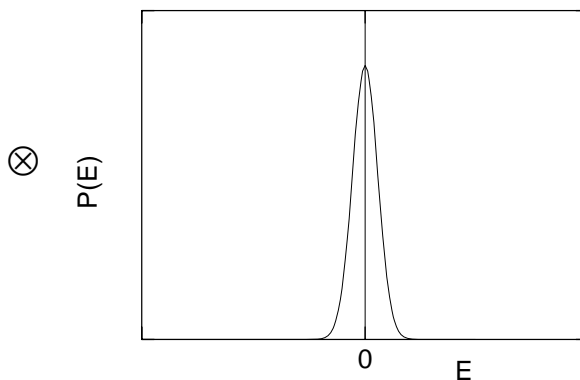
$$N_i = \sum_{j=0}^{N-1} H_{ij} \cdot \Phi_j$$

Another model

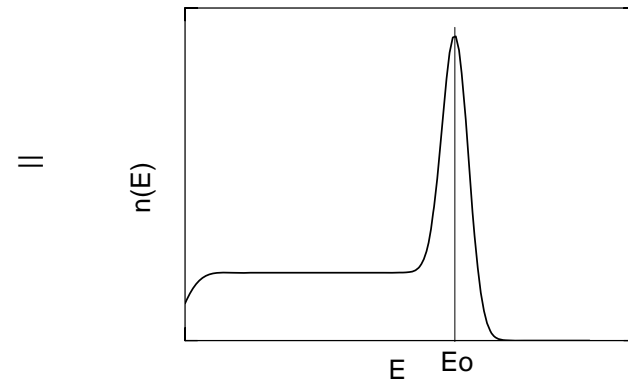
Distribution broadening applied to main peak and to charge sharing (more rigorous)



charge detection



distribution broadening



energy response

$$N(E) = \int_{-\infty}^{+\infty} P(E - E_0) \cdot \left[(1 - k)\Phi(E_0) + k \int_{E_0}^{+\infty} \frac{\Phi(E_1)}{E_1} dE_1 \right] dE_0$$

Estimation of the input spectrum

Problem : inversion of equation $N = H\Phi$

Method : iterative algorithm

$$\left\{ \begin{array}{l} \bar{\Phi}_{i+1} = \bar{\Phi}_i + k \cdot (N - H \bar{\Phi}_i) \quad (\text{Van Cittert}) \\ \bar{\Phi}_i = R \Phi_i \quad (\text{Regularization}) \end{array} \right.$$

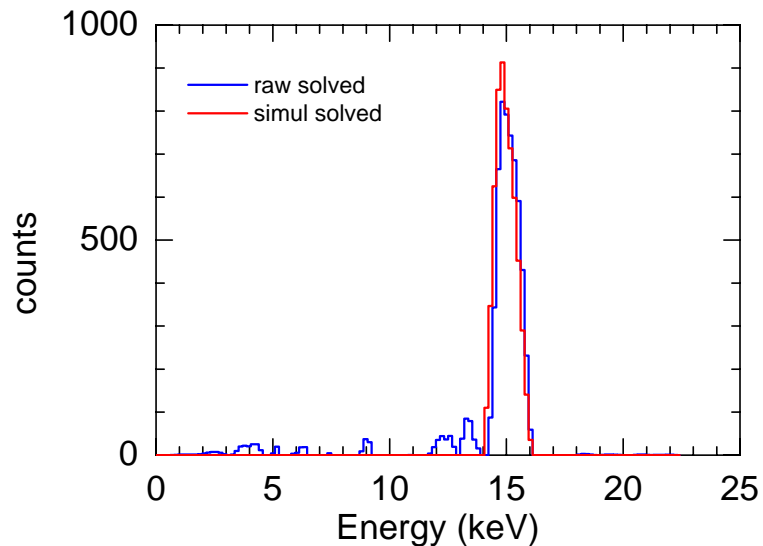
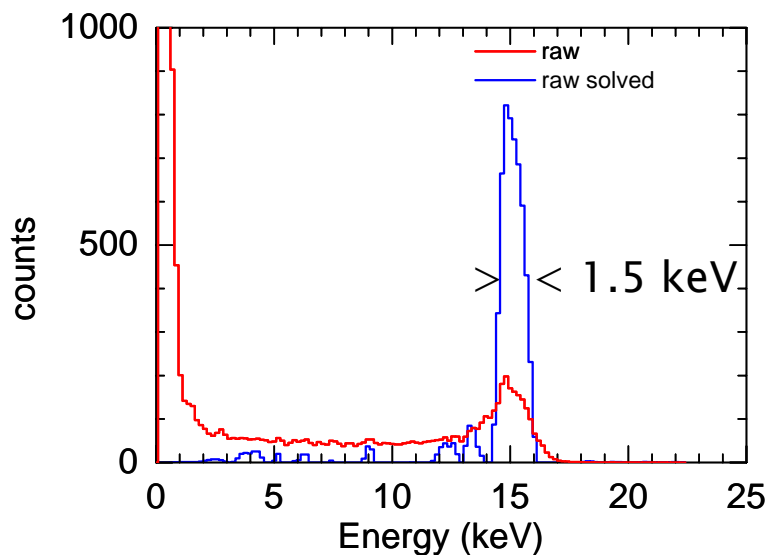
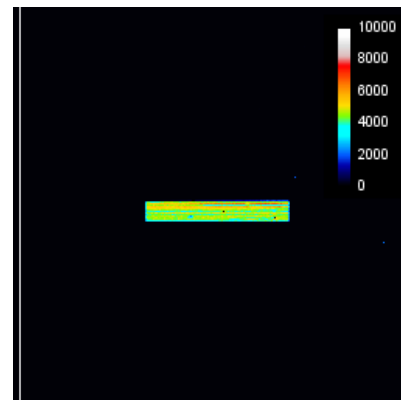
R : Regularization operator

- positivity (*a priori* information on Φ)
- “smoothness” (noise reduction)

15 keV monoenergetic beam

Multilayer mirror monochromator, 200 eV bandwidth
exposure 1 s/frame

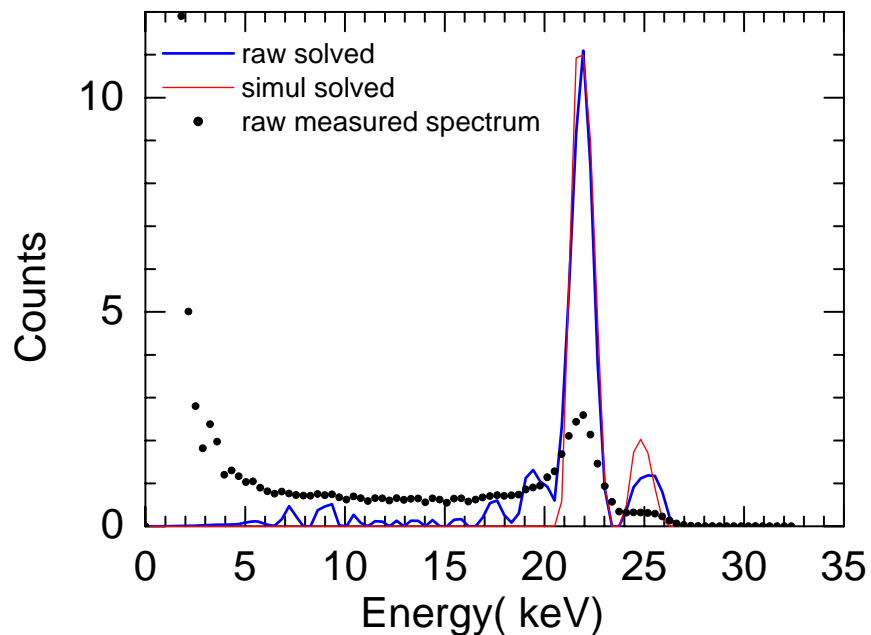
300 μm Si sensor



^{109}Cd source

300 μm Si sensor

Spectrum average over 130x130 pixels ROI

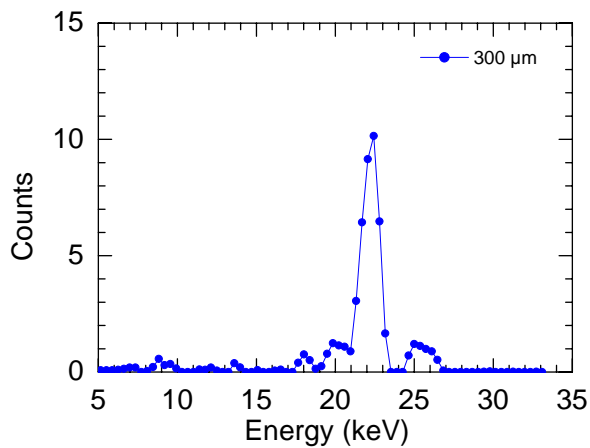


- Peaks 22.16 keV and 24.94 keV resolved
- E. resolution = 1.4 keV (peak FWHM)
- Residual low energy ripple
- Slight peak ratio mismatch (no Si absorption correction)

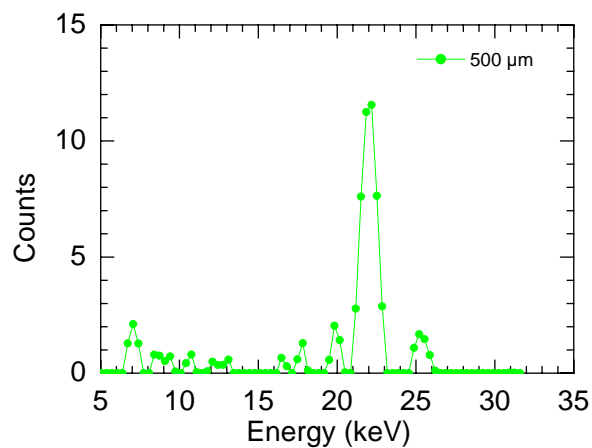
^{109}Cd source with different sensors

Reconstructed spectra

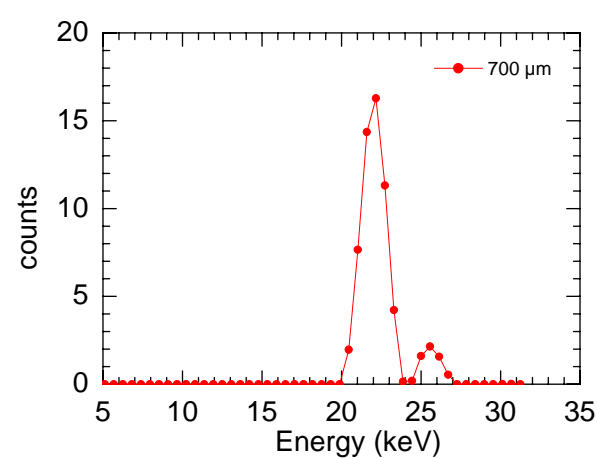
300 μm Si



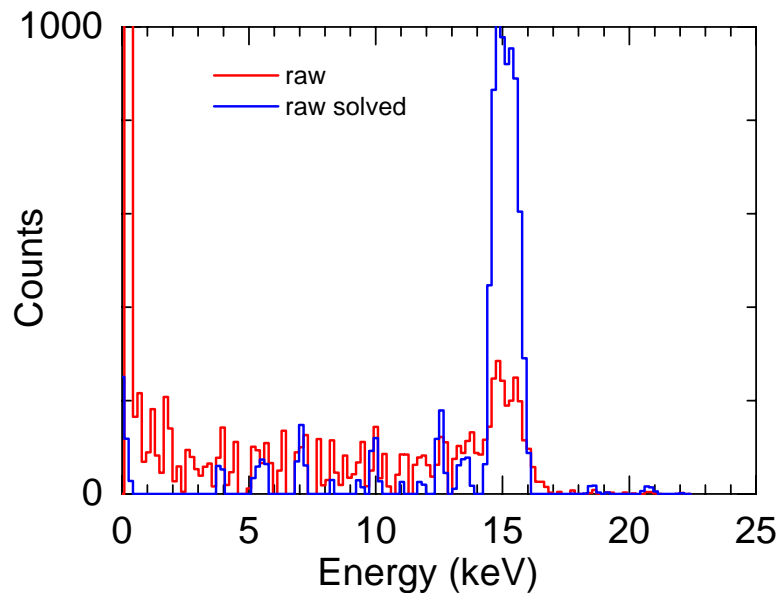
500 μm Si



700 μm Si



Single pixel 15 keV



~32 ms/pixel (1.7 GHz i386, 40–50 iterations)

→ ~35' for the whole image

→ ~9' for a 2x2 rebinned image

→ pixel-by-pixel spectrum reconstruction
slow but possible (color imaging)

raw pixel value : ~ 6800 counts (min. threshold)

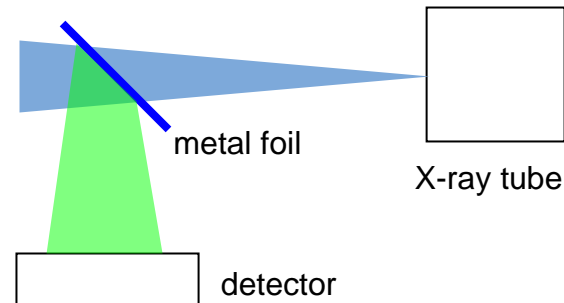
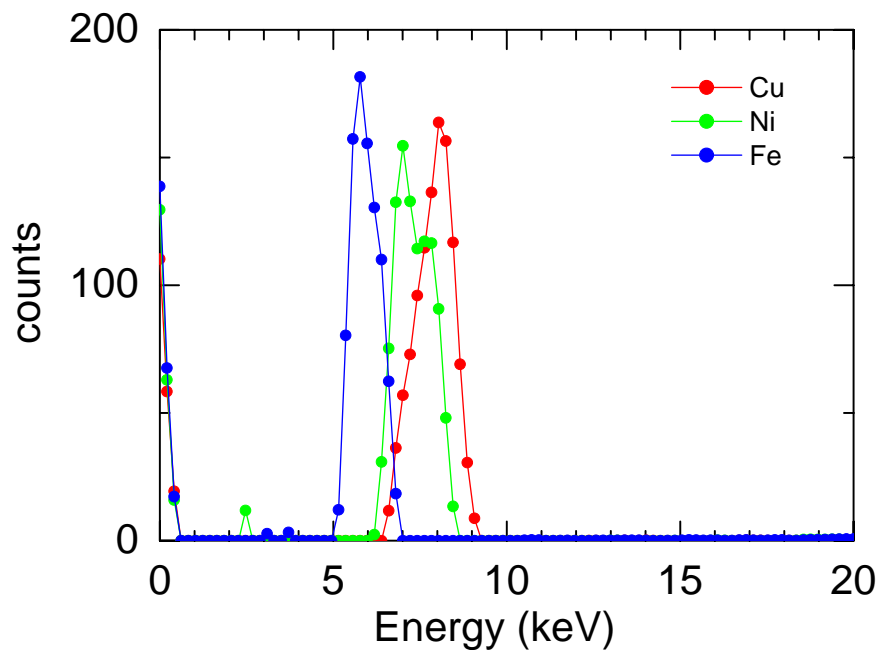
corrected peak integral : 7072 counts

Fluorescence spectra

Metal foils Fe 25 μm , Cu 50 μm , Ni 50 μm

Excitation : Mo X-ray tube 30 kV

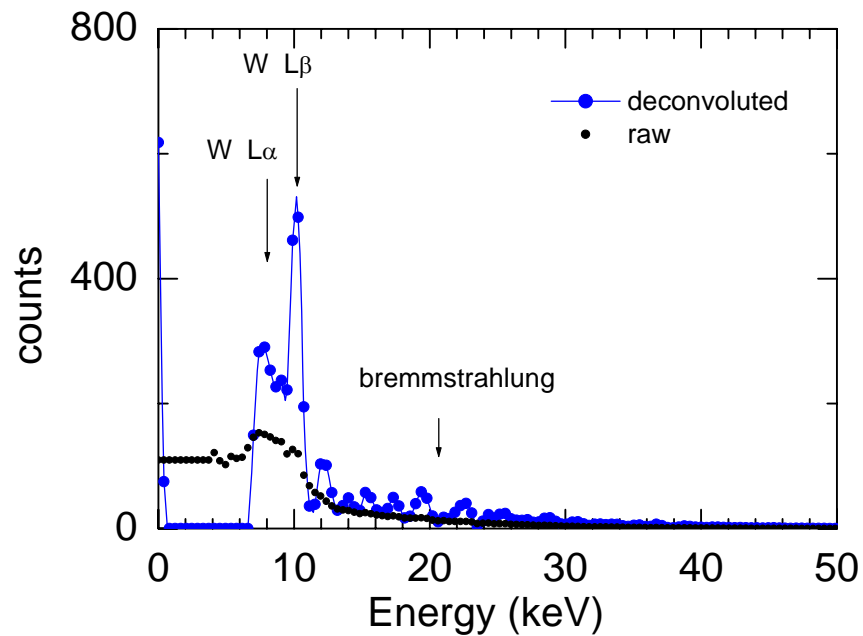
300 μm Si sensor



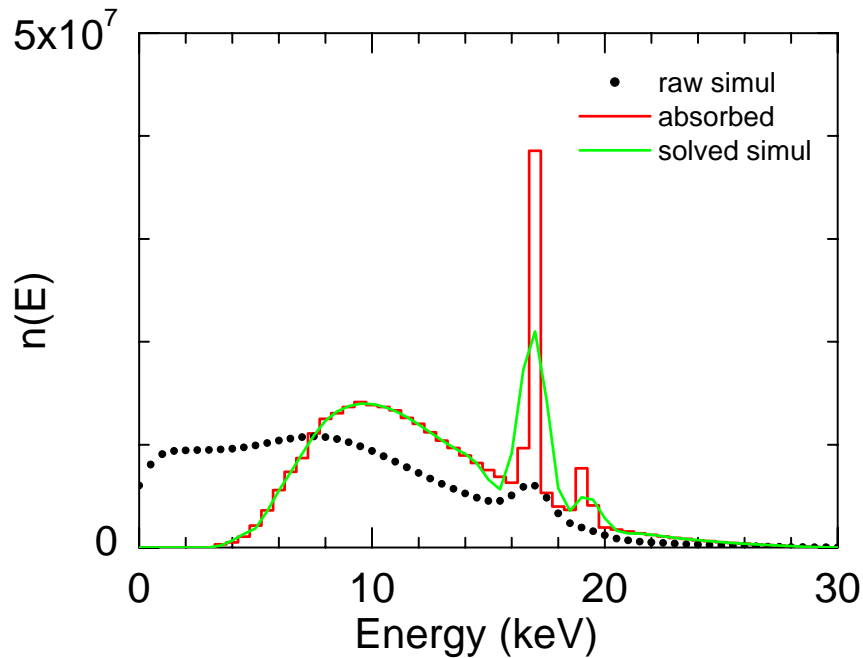
W anode

40 kV, 10 mA, Be window

300 μm Si sensor



Mo anode simulation



Mo anode spectrum Φ (30 kVp) simulated with XOP*

Raw measured spectrum = $N=H \Phi$

Reconstructed spectrum calculated by inversion algorithm

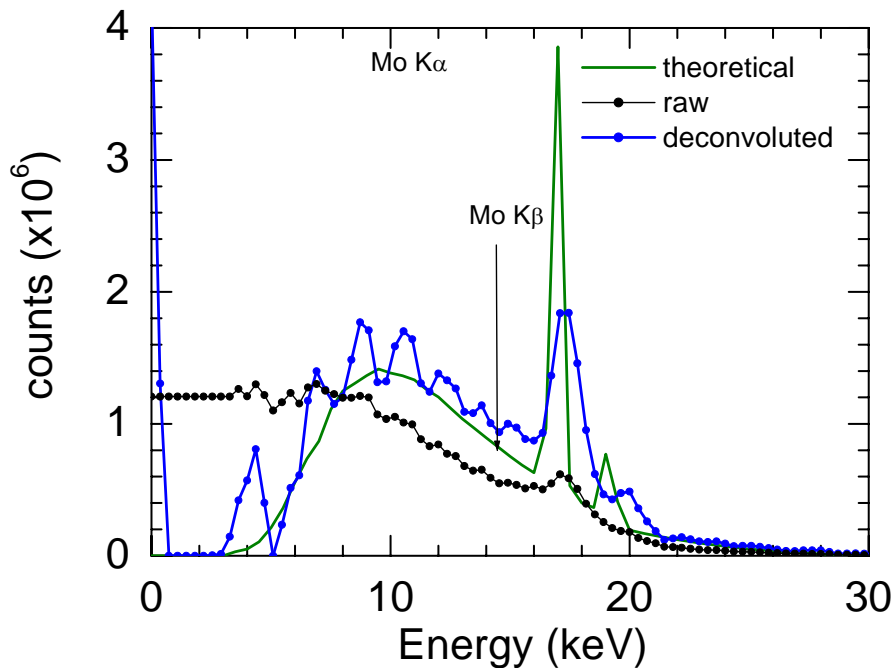
- Bremsstrahlung should be reconstructed
- 17.4 keV and 19.6 keV peaks should be resolved

*<http://www.esrf.eu/computing/scientific/xop2.1/>

Mo anode real spectra

30 kV, 10 mA, Be window

300 μm Si sensor



- K α (17.4 keV) and K β (19.6 keV) lines separated
- low energy ripple pattern (also present in raw spectrum)

Conclusions

Energy spectra corrected from charge sharing can be obtained from thresholds scan data using a deconvolution method

The method also provides improved energy resolution (peaks separation, peak/valley ratio)

Drawbacks :

- not applicable on low signal data (noise)
- long acquisition time (threshold scans)

Next steps :

- refine model
- explain ripple features in raw and reconstructed spectra
- attempt pixel by pixel processing
- compare with other methods

Acknowledgement

Medipix2 collaboration

Eric Ziegler (ESRF)

Joël Clément, Jean-Marie Rigal (ESRF)

Didier Ferrère, Daniel La Marra (Univ. Geneva)

Medipix chips

BM5 beamline

Readout system

Chipboards